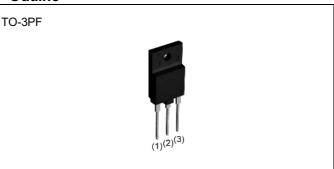
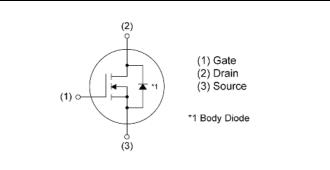


V <sub>DSS</sub>	600V
R <sub>DS(on)</sub> (Max.)	0.083Ω
Ι <sub>D</sub>	±50A
P <sub>D</sub>	120W

#### Outline



## Inner circuit



## Application

Features

2) Low on-resistance3) Fast switching speed

1) Fast reverse recovery time (trr)

4) Drive circuits can be simple

5) Pb-free plating ; RoHS compliant

Switching applications

## Packaging specifications

Packing	Tube
Packing code	C17
Marking	R6050JNZ
Quantity (pcs)	300

# • Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain - Source voltage	V <sub>DSS</sub>	600	V
Continuous drain current ( $T_c = 25^{\circ}C$ )	I <sub>D</sub> *1	±50	А
Pulsed drain current	I <sub>DP</sub> <sup>*2</sup>	±150	А
Gate - Source voltage	V <sub>GSS</sub>	±30	V
Avalanche current, single pulse	I <sub>AS</sub> *3	10	А
Avalanche energy, single pulse	E <sub>AS</sub> *3	1091	mJ
Power dissipation $(T_c = 25^{\circ}C)$	P <sub>D</sub>	120	W
Junction temperature	Tj	150	°C
Operating junction and storage temperature range	T <sub>stg</sub>	-55 to +150	°C

#### •Thermal resistance

Deremeter	Cumph of	Values			l loit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub>	-	-	1.03	°C/W
Thermal resistance, junction - ambient	R <sub>thJA</sub>	-	-	40	°C/W
Soldering temperature, wavesoldering for 10s	T <sub>sold</sub>	-	-	265	°C

# •Electrical characteristics (T<sub>a</sub> = 25°C)

Deremeter	Sumpleal	Conditions	Values			Lipit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Drain - Source breakdown voltage	$V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$		600	-	-	V	
Zero gate voltage drain current	I <sub>DSS</sub>	$V_{DS} = 600V, V_{GS} = 0V$ $T_j = 25^{\circ}C$	-	-	100	μA	
Gate - Source leakage current	I <sub>GSS</sub>	$V_{GS}$ = ±30V, $V_{DS}$ = 0V	-	-	±100	nA	
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 5.0 \text{mA}$	5.0	6.0	7.0	V	
Static drain - source on - state resistance	R <sub>DS(on)</sub> *5	$V_{GS}$ = 15V, I <sub>D</sub> = 25A T <sub>j</sub> = 25°C	-	0.064	0.083	Ω	
Gate resistance	R <sub>G</sub>	f = 1MHz, open drain	-	1.2	-	Ω	



# • Electrical characteristics (T<sub>a</sub> = 25°C)

Deremeter	Cump of	Conditions	Values			Unit	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	4500	-		
Output capacitance	C <sub>oss</sub>	V <sub>DS</sub> = 100V	-	230	-		
Reverse transfer capacitance	C <sub>rss</sub>	f = 1MHz	-	3.5	-	_	
Effective output capacitance energy related	C <sub>o(er)</sub> *6	V <sub>GS</sub> = 0V	-	190	-	pF	
Effective output capacitance time related	C <sub>o(tr)</sub> *7	$V_{DS} = 0V$ to 480V	-	760	-		
Turn - on delay time	t <sub>d(on)</sub> *5	$V_{DD} \simeq 300$ V, $V_{GS}$ = 15V	-	45	-		
Rise time	t <sub>r</sub> *5	I <sub>D</sub> = 25A	-	35	-	20	
Turn - off delay time	$t_{d(off)}^{*5}$	$R_L \simeq 12\Omega$	-	120	-	ns	
Fall time	t <sub>f</sub> *5	R <sub>G</sub> = 10Ω	-	50	-		

# • Gate charge characteristics ( $T_a = 25^{\circ}C$ )

Deremeter	Cumphal	Conditions	Values			Unit	
Parameter	Symbol Conditions		Min.	Тур.	Max.	UIII	
Total gate charge	$Q_g^{*5}$	$V_{DD} \simeq 300 V$	-	120	-		
Gate - Source charge	$Q_{gs}^{*5}$	I <sub>D</sub> = 50A	-	40	-	nC	
Gate - Drain charge	${\sf Q}_{\sf gd}{}^{*5}$	V <sub>GS</sub> = 15V	-	40	-		
Gate plateau voltage	V <sub>(plateau)</sub>	$V_{DD} \simeq 300$ V, I <sub>D</sub> = 50A	-	9.3	-	V	

\*1 Limited only by maximum temperature allowed.

\*2 Pw  $\leq$  10µs, Duty cycle  $\leq$  1%

- \*3 L  $\simeq$  20mH, V<sub>DD</sub> = 50V, R<sub>G</sub> = 25 $\Omega$ , starting T<sub>i</sub> = 25°C
- \*4 Tc=25°C
- \*5 Pulsed
- \*6 Co(er) is a fixed capacitance that gives the same stored energy as Coss while  $V_{DS}$  is rising from 0 to 80%  $V_{DSS}$ .
- \*7 Co(tr) is a fixed capacitance that gives the same charging time as Coss while  $V_{DS}$  is rising from 0 to 80%  $V_{DSS}$ .



# •Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Deremeter	Symbol	Conditions	Values			Unit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Source current	I <sub>S</sub> *1		-	-	50	А
Pulsed source current	$I_{SP}^{*2}$	T <sub>C</sub> = 25°C	-	-	150	А
Source-Drain voltage	$V_{SD}^{*5}$	V <sub>GS</sub> = 0V, I <sub>S</sub> = 50A	-	-	1.7	V
Reverse recovery time	t <sub>rr</sub> *5		-	120	-	ns
Reverse recovery charge	Q <sub>rr</sub> *5	$Q_{rr}^{*5}$ $I_{S} = 50A$ di/dt = 100A/µs	-	500	-	nC
Peak reverse recovery current	۱ <sub>.۳</sub> *5		-	8.8	-	А



#### • Electrical characteristic curves

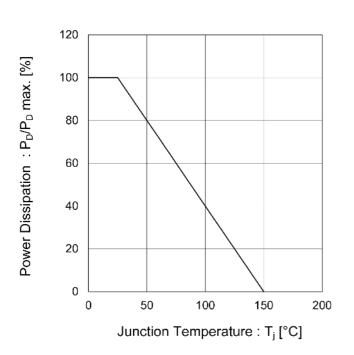
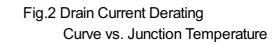


Fig.1 Power Dissipation Derating Curve



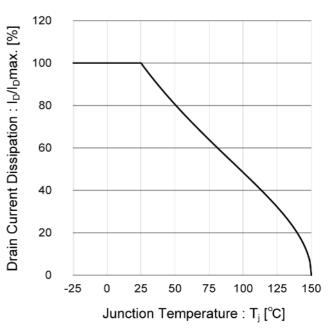


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

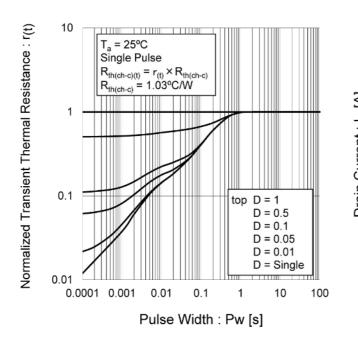
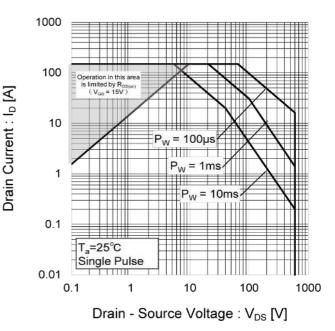


Fig.4 Maximum Safe Operating Area





# • Electrical characteristic curves

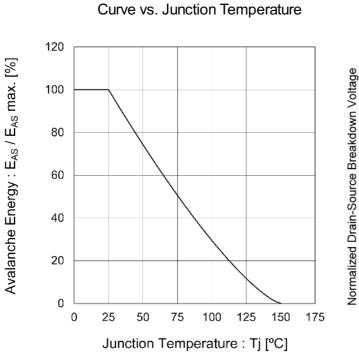


Fig.5 Avalanche Energy Derating

# Fig.6 Normalized Breakdown Voltage vs. Junction Temperature

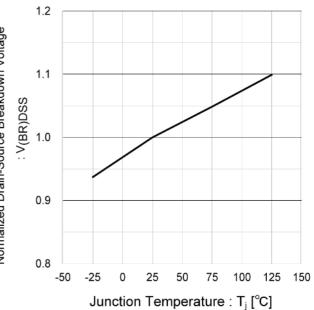


Fig.7 Typical Output Characteristics(I)

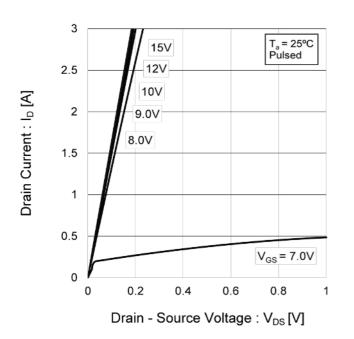
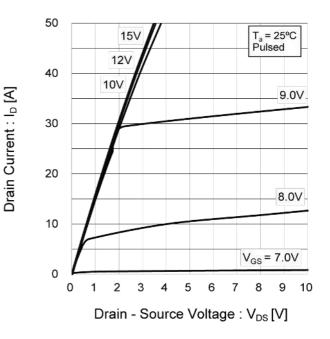
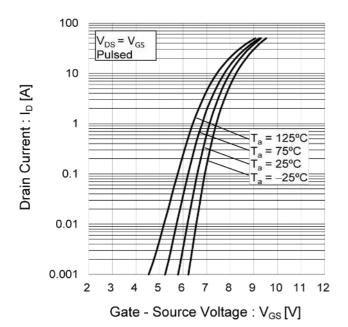


Fig.8 Typical Output Characteristics(II)



#### Electrical characteristic curves



## Fig.9 Typical Transfer Characteristics

Fig.10 Normalized Gate Threshold . Voltage vs Junction Temperature

Datasheet

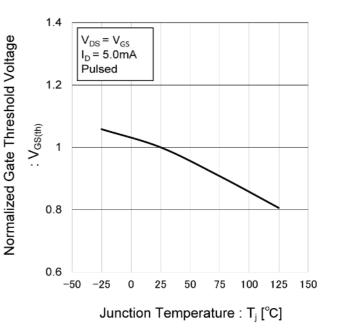
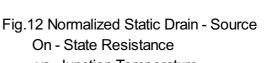
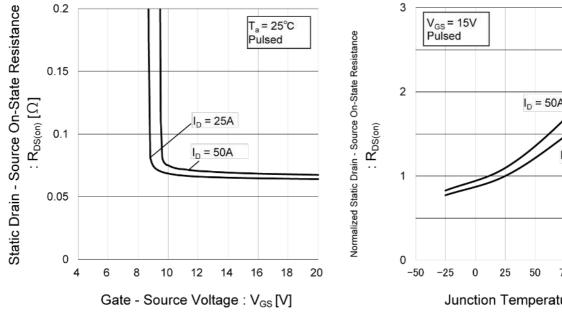
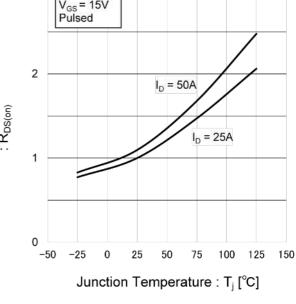


Fig.11 Static Drain - Source On - State Resistance vs. Gate Source Voltage





# vs. Junction Temperature



# •Electrical characteristic curves

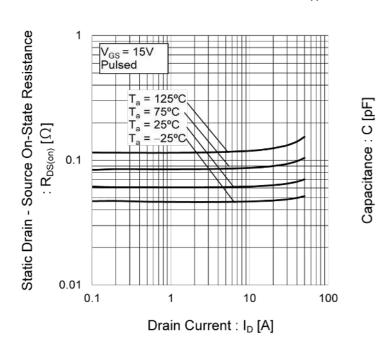


Fig.13 Static Drain - Source On - State Resistance vs. Drain Current(I)

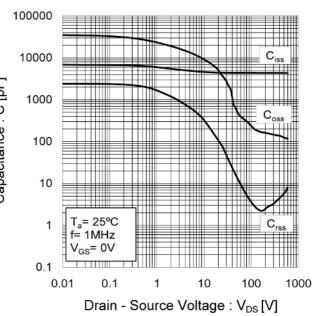
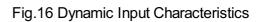


Fig.14 Typical Capacitance vs. Drain - Source Voltage



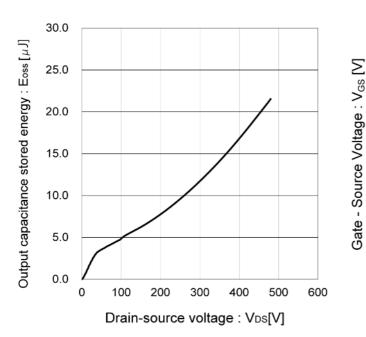
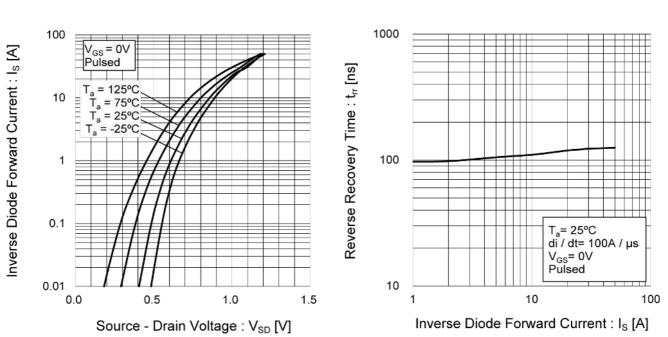


Fig.15 Typical Coss Stored Energy

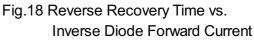
15 = 25°C , DD= 300V I<sub>D</sub>= 50A 12 Pulsed 9 6 3 0 0 20 40 60 80 140 100 120 Total Gate Charge : Qg [nC]



#### • Electrical characteristic curves



# Fig.17 Inverse Diode Forward Current vs. Source - Drain Voltage





### Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

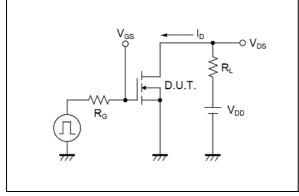
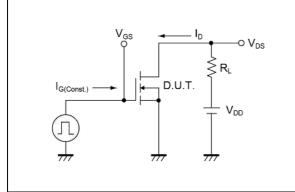


Fig.2-1 Gate Charge Measurement Circuit



#### Fig.3-1 Avalanche Measurement Circuit

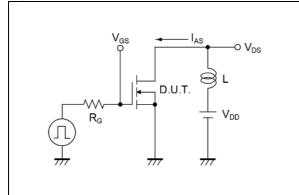


Fig.4-1 Diode Recovery Measurement Circuit

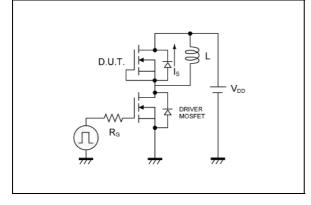
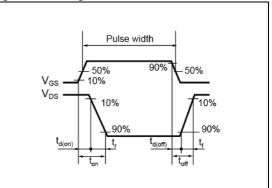
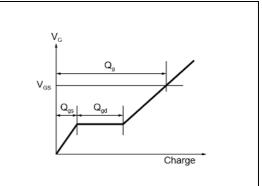


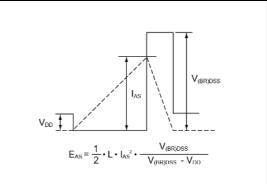
Fig.1-2 Switching Waveforms



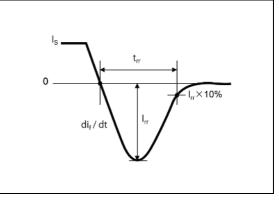
#### Fig.2-2 Gate Charge Waveform



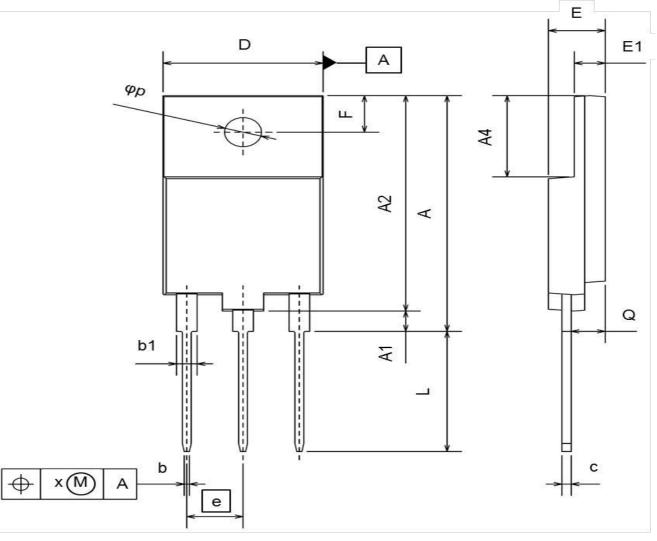
#### Fig.3-2 Avalanche Waveform



## Fig.4-2 Diode Recovery Waveform

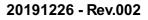


# Dimensions



DIM	MILIMETERS		INC	HES
	MIN	MAX	MIN	MAX
A	28.60	29.40	1.126	1.157
A1	2.30	2.70	0.091	0.106
A2	26.30	26.70	1.035	1.051
A4	9.80	10.20	0.386	0.402
b	0.66	0.95	0.026	0.037
b1	1.80	2.20	0.071	0.087
С	0.80	1.00	0.031	0.039
D	15.30	15.70	0.602	0.618
E	5.30	5.70	0.209	0.224
E1	2.80	3.20	0.110	0.126
е	5.4	45	0.215	
F	4.35	4.65	0.171	0.183
L	14.60	15.00	0.575	0.591
φp	3.40	3.80	0.134	0.150
Q	3.10	3.50	0.122	0.138
Х	-	0.50		0.020

Dimension in mm / inches



# Notice

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1. Our Products are designed and manufactured for application in ordinary electronic equipment (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment (<sup>Note 1)</sup>, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications
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JAPAN	USA	EU	CHINA
CLASSⅢ	CLASSⅢ	CLASS II b	CLASSII
CLASSⅣ	CLASSIII	CLASSⅢ	CLASSI

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  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

#### **Precaution for Product Label**

A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

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#### Precaution for Foreign Exchange and Foreign Trade act

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